# BLM7G1822S-20PB; BLM7G1822S-20PBG LDMOS 2-stage power MMIC

**AMMPLEON** 

Rev. 6 — 28 September 2018

Product data sheet

### **Product profile**

#### 1.1 General description

The BLM7G1822S-20PB(G) is a dual section, 2-stage power MMIC using Ampleon's state of the art GEN7 LDMOS technology. This multiband device is perfectly suited as general purpose driver or small cell final in the frequency range from 1805 MHz to 2170 MHz. Available in gull wing or straight lead outline.

#### Table 1. **Performance**

Typical RF performance at  $T_{case}$  = 25 °C;  $I_{Dq1}$  = 27 mA;  $I_{Dq2}$  = 76 mA. Test signal: 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF; per section unless otherwise specified in a class-AB production circuit.

Test signal	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	Gp	η <sub>D</sub>	ACPR <sub>5M</sub>
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA	2167.5	28	2	32.3	23	-41

#### 1.2 Features and benefits

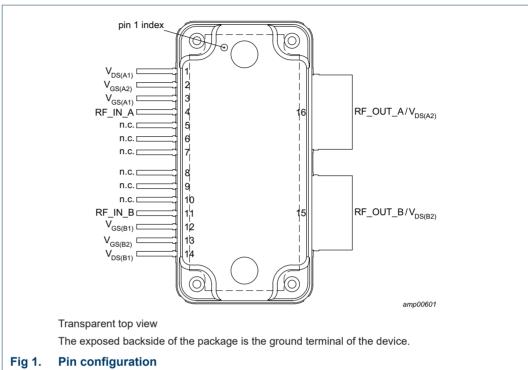
- Designed for broadband operation (frequency 1805 MHz to 2170 MHz)
- High section-to-section isolation enabling multiple combinations
- Integrated temperature compensated bias
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- On-chip matching for ease of use
- For RoHS compliance see the product details on the Ampleon website

#### 1.3 Applications

- RF power MMIC for multi-carrier and multi-standard GSM, W-CDMA and LTE base stations in the 1805 MHz to 2170 MHz frequency range. Possible circuit topologies are the following as also depicted in Section 8.1:
  - Dual section or single ended
  - Doherty
  - Quadrature combined
  - Push-pull

### 2. Pinning information

### 2.1 Pinning



#### \_\_\_\_\_\_

### 2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V <sub>DS(A1)</sub>	1	drain-source voltage of driver stage A1
V <sub>GS(A2)</sub>	2	gate-source voltage of final stage A2
V <sub>GS(A1)</sub>	3	gate-source voltage of driver stage A1
RF_IN_A	4	RF input section A
n.c.	5	not connected
n.c.	6	not connected
n.c.	7	not connected
n.c.	8	not connected
n.c.	9	not connected
n.c.	10	not connected
RF_IN_B	11	RF input section B
V <sub>GS(B1)</sub>	12	gate-source voltage of driver stage B1
V <sub>GS(B2)</sub>	13	gate-source voltage of final stage B2
V <sub>DS(B1)</sub>	14	drain-source voltage of driver stage B1

Table 2. Pin description ...continued

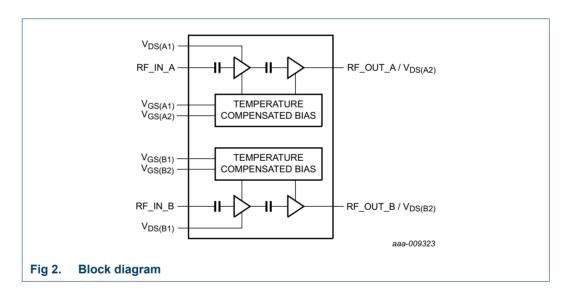
Symbol	Pin	Description
RF_OUT_B/V <sub>DS(B2)</sub>	15	RF output section B / drain-source voltage of final stage B2
RF_OUT_A/V <sub>DS(A2)</sub>	16	RF output section A / drain-source voltage of final stage A2
GND	flange	RF ground

### 3. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	ame Description					
BLM7G1822S-20PB	-	plastic, heatsink small outline package; 16 leads (flat)	SOT1211-3				
BLM7G1822S-20PBG	-	plastic, heatsink small outline package; 16 leads	SOT1212-3				

### 4. Block diagram



### 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C
T <sub>case</sub>	case temperature		-	150	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

#### Thermal characteristics

#### **Thermal characteristics** Table 5.

Measured for total device.

Symbol	Parameter	Conditions	Value	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	final stage; T <sub>case</sub> = 90 °C; P <sub>L</sub> = 3.56 W	1.9	K/W
		driver stage; T <sub>case</sub> = 90 °C; P <sub>L</sub> = 3.56 W	6.2	K/W

<sup>[1]</sup> When operated with a CW signal.

#### **Characteristics**

#### Table 6. DC characteristics

T<sub>case</sub> = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Final stag	е						<u> </u>
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 150.8 \mu\text{A}$		65	-	-	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 28 \text{ V}; I_D = 76 \text{ mA}$		1.5	2	2.5	V
		V <sub>DS</sub> = 28 V; I <sub>D</sub> = 76 mA	<u>[1]</u>	1.7	2.65	3.6	V
$\Delta I_{Dq}/\Delta T$	quiescent drain current variation with temperature	-40 °C ≤ T <sub>case</sub> ≤ +85 °C	[1]	-	±1	-	%
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V		-	-	1.4	μА
I <sub>DSX</sub>	drain cut-off current	V <sub>GS</sub> = 5.55 V; V <sub>DS</sub> = 10 V		-	2.8	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 1.0 V; V <sub>DS</sub> = 0 V		-	-	140	nA
Driver sta	ge						
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 30.16 \mu\text{A}$		65	-	-	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 27 mA		1.6	2.1	2.6	V
		V <sub>DS</sub> = 28 V; I <sub>D</sub> = 27 mA	[2]	1.9	2.85	3.8	V
$\Delta I_{Dq}/\Delta T$	quiescent drain current variation with temperature	-40 °C ≤ T <sub>case</sub> ≤ +85 °C	[2]	-	±1	-	%
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V		-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	V <sub>GS</sub> = 5.55 V; V <sub>DS</sub> = 10 V		-	0.55	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 1.0 V; V <sub>DS</sub> = 0 V		-	-	140	nA

<sup>[1]</sup> In production circuit with 1105  $\Omega$  gate feed resistor.

<sup>[2]</sup> In production circuit with 765  $\Omega$  gate feed resistor.

#### Table 7. RF Characteristics

Typical RF performance at  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 27 mA;  $I_{Dq2}$  = 76 mA;  $P_{L(AV)}$  = 2 W. Per section unless otherwise specified, measured in an Ampleon wideband f = 1807.5 MHz to 2167.5 MHz straight lead production circuit.

Parameter	Conditions	Min	Тур	Max	Unit
II: single carrier W-CDMA [1]		<u> </u>			
power gain	f = 1807.5 MHz	-	34	-	dB
	f = 2167.5 MHz	30.8	32.3	33.8	dB
drain efficiency	f = 1807.5 MHz	-	22	-	%
	f = 2167.5 MHz	20	23	-	%
input return loss	f = 2167.5 MHz	-	-19	-10	dB
adjacent channel power ratio (5 MHz)	f = 1807.5 MHz	-	-41	-	dBc
	f = 2167.5 MHz	-	-41	-37	dBc
output peak-to-average ratio	f = 1807.5 MHz	-	8.4	-	dB
	f = 2167.5 MHz	7.2	8.4	-	dB
quiescent drain current variation with	T = -40 °C to +85 °C				
temperature	final stage $I_{Dq}$ ; gate feed resistor = 1105 $\Omega$	-	±1	-	%
	driver stage $I_{Dq}$ ; gate feed resistor = 765 $\Omega$	-	±1	-	%
I: CW [2]		'			
phase response difference	between sections	-10	-	+10	deg
insertion power gain difference	between sections	-0.5	-	+0.5	dB
	power gain  drain efficiency  input return loss  adjacent channel power ratio (5 MHz)  output peak-to-average ratio  quiescent drain current variation with temperature  I: CW [2]  phase response difference	Single carrier W-CDMA   11   12   13   14   15   15   16   15   16   16   16   16	Single carrier W-CDMA   1	Single carrier W-CDMA   Sin	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

<sup>[1] 3</sup>GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF.

### 8. Application information

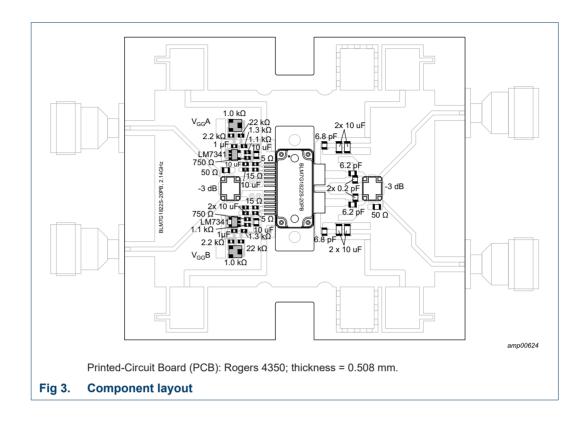
#### Table 8. Typical performance

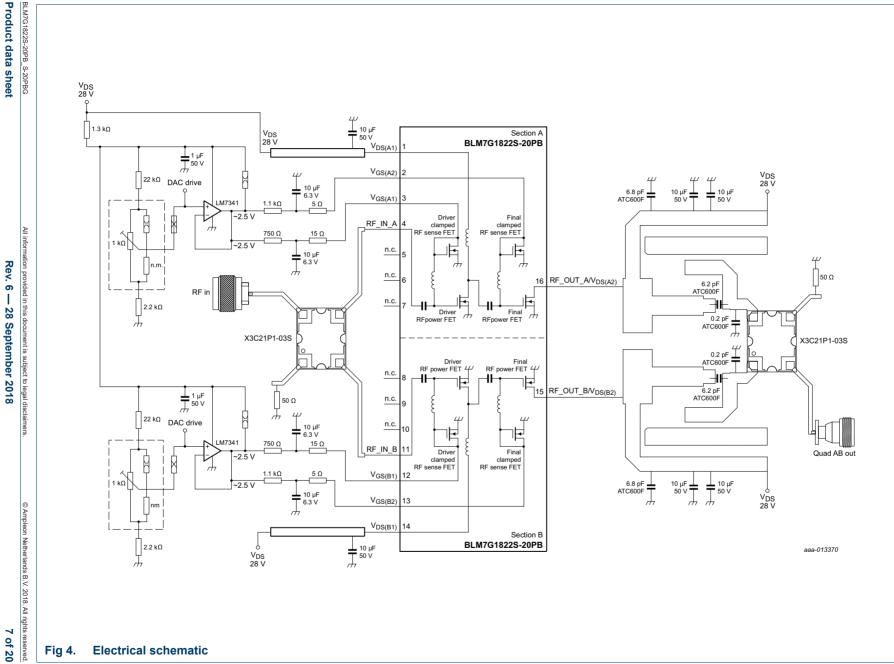
Test signal: 1-tone CW; RF performance at  $T_{\text{case}}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 45 mA (both sections);  $I_{Dq2}$  = 140 mA (both sections) unless otherwise specified, measured in an Ampleon f = 2110 MHz to 2170 MHz straight lead class AB application circuit (see Figure 3 for the component layout and Figure 4 for the electrical schematic).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	f = 2140 MHz	-	43.5	-	dBm
P <sub>L(3dB)</sub>	output power at 3 dB gain compression	f = 2140 MHz	-	44.1	-	dBm
$\eta_{D}$	drain efficiency	at P <sub>L(1dB)</sub> ; f = 2140 MHz	-	47.6	-	%
Gp	power gain	P <sub>L(AV)</sub> = 1.585 W; f = 2140 MHz	-	31.5	-	dB
B <sub>video</sub>	video bandwidth	2-tone CW; P <sub>L(AV)</sub> = 1.585 W; f = 2140 MHz	-	170	-	MHz
G <sub>flat</sub>	gain flatness	over a frequency range of 60 MHz; P <sub>L(AV)</sub> = 1.585 W	-	0.4	-	dB
ΔG/ΔT	gain variation with temperature	f = 2140 MHz	-	0.03	-	dB/°C
$ s_{12} ^2$	isolation	between sections A and B; [1] P <sub>L(AV)</sub> = 1.585 W; f = 2140 MHz	-	28.5	-	dB
K	Rollett stability factor	T = -40 °C; f = 0.1 GHz to 3 GHz	-	>1	-	

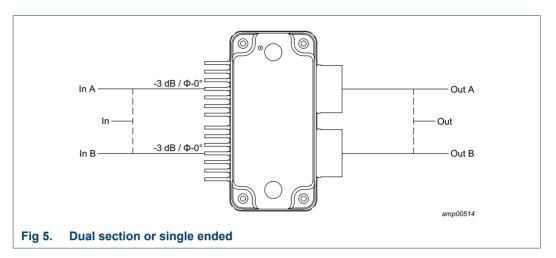
<sup>[1]</sup> Measured on dual section evaluation board  $I_{Dq1}$  = 40 mA (both sections);  $I_{Dq2}$  = 150 mA (both sections).

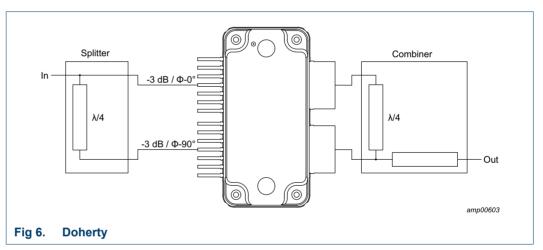
<sup>[2]</sup> f = 2170 MHz.

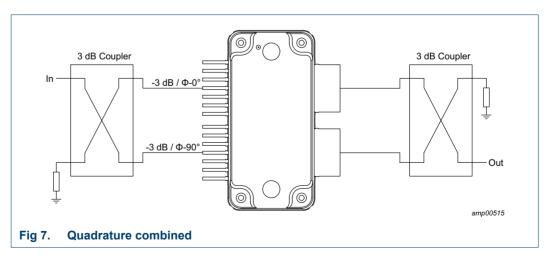


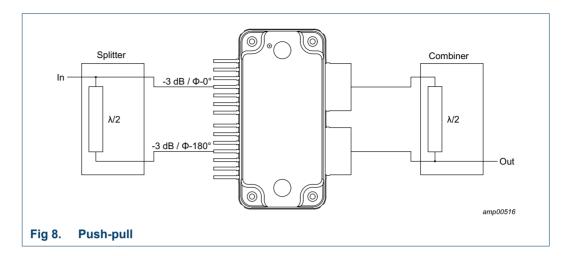


### 8.1 Possible circuit topologies









### 8.2 Ruggedness in class-AB operation

The BLM7G1822S-20PB and BLM7G1822S-20PBG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 32 V;  $I_{Dq1}$  = 20 mA (per section);  $I_{Dq2}$  = 75 mA (per section);  $P_{i}$  = 16 dBm (CW and corresponding to  $P_{L(3dB)}$  under  $Z_{S}$  = 50  $\Omega$  load); f = 2140 MHz.

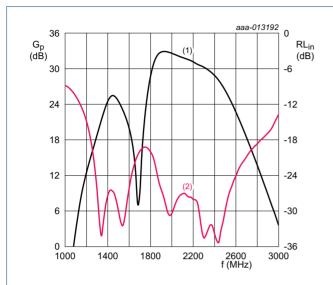
#### 8.3 Impedance information

Table 9. Typical impedance at 3 dB compression point

Measured load-pull data per section; test signal: pulsed CW;  $T_{case} = 25$  °C;  $V_{DS} = 28$  V;  $I_{Dq1} = 20$  mA;  $I_{Dq2} = 65$  mA;  $I_{Dq2} = 65$  mA;  $I_{Dq2} = 65$  mA;  $I_{Dq2} = 65$  mA;  $I_{Dq3} = 100$  μs;  $I_{Dq3} =$ 

	tuned for maximum output power					tuned for maximum efficiency					
f	Z <sub>L</sub>	G <sub>p(max)</sub>	PL	$\eta_{\text{add}}$	AM-PM conversion	Z <sub>L</sub>	G <sub>p(max)</sub>	P <sub>L</sub>	$\eta_{\text{add}}$	AM-PM conversion	
(MHz)	(Ω)	(dB)	(dBm)	(%)	(deg)	(Ω)	(dB)	(dBm)	(%)	(deg)	
BLM7G	1822S-20PB	•			·						
1700	15.3 – j14.5	33.2	42.7	50.6	8.3	28.5 – j20.2	34.6	41.6	56.5	9.2	
1800	16.3 – j11.7	32.9	42.7	50.8	6.3	31.3 – j8.60	34.1	41.6	57.1	7.0	
1900	16.1 – j9.70	32.1	42.8	50.8	6.1	26.5 – j0.01	33.3	41.7	57.3	6.9	
2000	15.5 – j8.10	31.5	42.8	50.1	6.1	21.0 + j2.20	32.6	42.0	56.4	7.3	
2100	14.4 – j6.90	31.5	42.9	50.0	6.9	15.6 + j2.00	32.9	42.1	55.8	8.6	
2200	13.7 – j6.60	31.7	42.7	49.8	8.5	12.3 + j1.20	33.0	41.6	54.3	9.6	
2300	12.8 – j6.80	31.4	42.5	49.1	10.6	10.0 + j0.10	32.5	41.3	53.6	10.3	
BLM7G	1822S-20PBG				·						
1700	15.8 – j16.1	33.5	42.5	52.9	9.2	28.9 – j21.8	35.1	41.6	57.9	11.1	
1800	16.5 – j13.8	32.9	42.5	51.2	7.7	30.6 – j11.6	34.2	41.6	56.8	8.4	
1900	16.7 – j12.4	32.2	42.5	50.2	7.2	27.9 – j4.64	33.5	41.7	55.9	7.8	
2000	16.3 – j9.74	31.7	42.5	51.2	7.3	20.4 + j0.45	32.7	41.7	55.6	9.0	
2100	15.6 – j8.61	31.5	42.6	52.0	9.5	15.9 + j0.68	32.6	41.7	56.5	11.8	
2200	14.6 – j8.87	31.3	42.5	49.7	10.3	12.7 – j0.44	32.4	41.6	53.8	12.1	
2300	13.4 – j9.32	30.5	42.4	48.2	12.8	10.7 – j1.98	31.7	41.6	53.7	13.2	

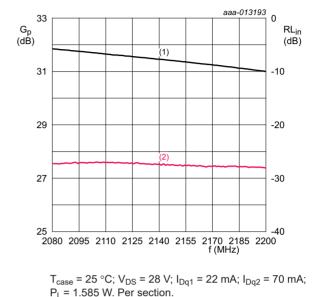
#### 8.4 Graphs



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 22 mA;  $I_{Dq2}$  = 70 mA;  $P_{I}$  = 1.585 W. Per section.

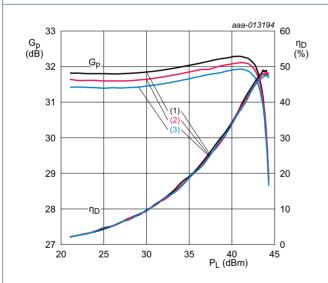
- (1) magnitude of G<sub>p</sub>
- (2) magnitude of RLin

Fig 9. Wideband power gain and input return loss as function of frequency; typical values



- (1) magnitude of G<sub>p</sub>
- (2) magnitude of RLin

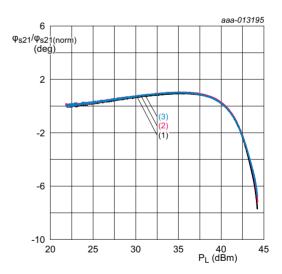
Fig 10. In-band power gain and input return loss as function of frequency; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 22 mA;  $I_{Dq2}$  = 70 mA. Per section.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

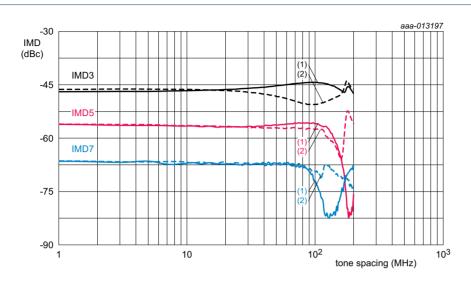
Fig 11. Power gain and drain efficiency as function of output power; typical values



Normalized at P<sub>L</sub> = 22 dBm;  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 22 mA;  $I_{Dq2}$  = 70 mA. Per section.

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

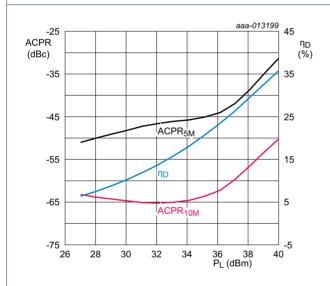
Fig 12. Normalized phase response as a function of output power; typical values



 $T_{case} = 25 \, ^{\circ}\text{C}; V_{DS} = 28 \, \text{V}; I_{Dq1} = 22 \, \text{mA}; I_{Dq2} = 70 \, \text{mA}; f = 2140 \, \text{MHz}; 2-tone CW; P_{L(AV)} = 0.25 \, \text{W}. Per section.$ 

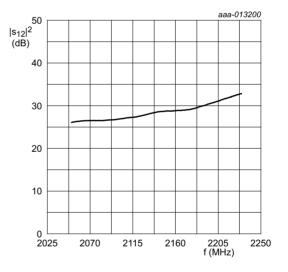
- (1) IMD low
- (2) IMD high

Fig 13. Intermodulation distortion as a function of tone spacing; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 22 mA;  $I_{Dq2}$  = 70 mA; f = 2140 MHz; 1-carrier W-CDMA; test model 1; PAR = 7.2 dB at 0.01 % probability on CCDF. Per section.





 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 20 mA;  $I_{Dq2}$  = 75 mA. Per section. Measured on evaluation board.

Fig 15. Isolation as a function of frequency; typical values

### 9. Package outline

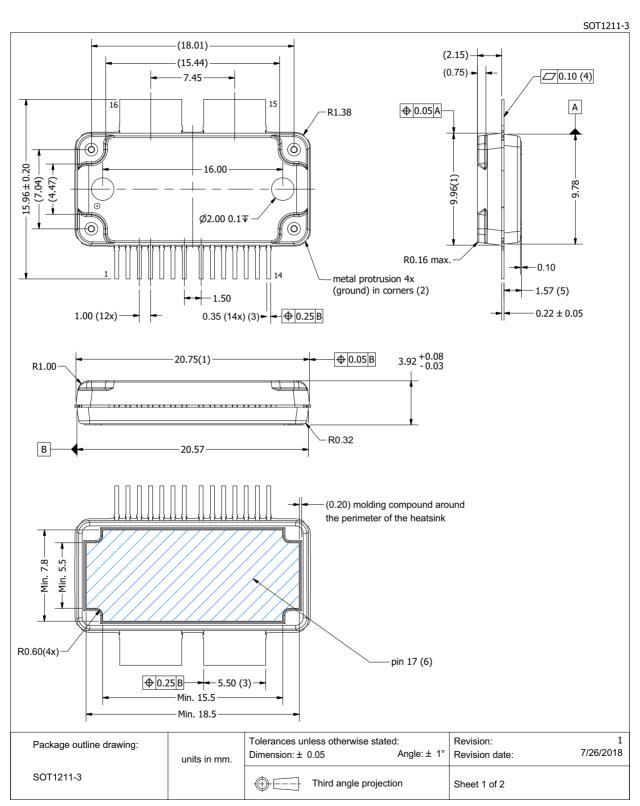


Fig 16. Package outline SOT1211-3 (sheet 1 of 2)

SOT1211-3

Drawing Notes						
Items	Description					
	Dimensions are excluding mold protrusion. Areas located adjacent to the leads have a maximum mold protrusion of 0.25					
(1)	mm (per side) and 0.62 mm max. in length. In between the 14 leads the protrusion is 0.25 mm. max. At all other areas the					
	mold protrusion is maximum 0.15 mm per side. See also detail B.					
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).					
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location					
(4)	The lead coplanarity over all leads is 0.1 mm maximum.					
(5)	Dimension is measured 0.5 mm from the edge of the top package body.					
(6)	The hatched area indicates the exposed metal heatsink.					
(7)	The leads and exposed heatsink are plated with matte Tin (Sn).					

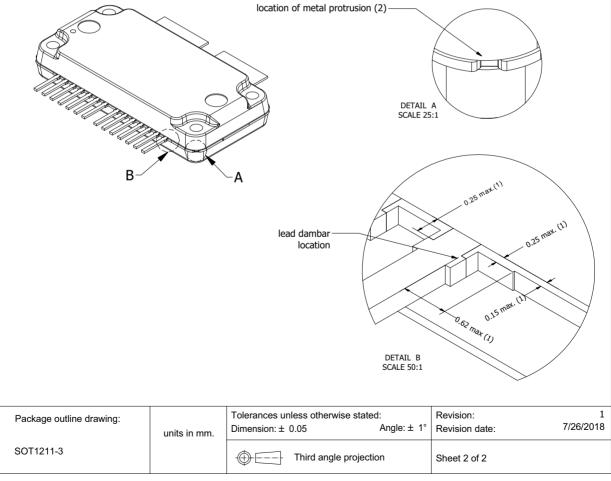


Fig 17. Package outline SOT1211-3 (sheet 2 of 2)

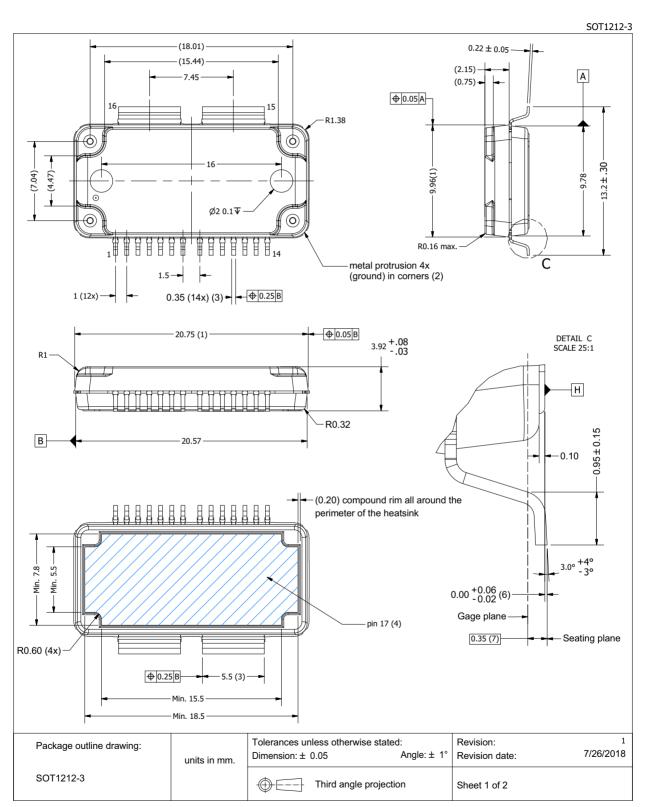


Fig 18. Package outline SOT1212-3 (sheet 1 of 2)

SOT1212-3

	Drawing Notes							
Items	Description							
	Dimensions are excluding mold protrusion. Areas located adjacent to the leads have a maximum mold protrusion of 0.25							
(1)	mm (per side) and 0.62 mm max. in length. In between the 14 leads the protrusion is 0.25 mm max. At all other areas the							
	mold protrusion is maximum 0.15 mm per side. See also detail B.							
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).							
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.							
(4)	The hatched area indicated the exposed heatsink.							
(5)	The leads and exposed heatsink are plated with matte Tin (Sn).							
(6)	Dimension is measured with respect to the bottom of the heatsink Datum H. Positive value means that the bottom of the							
(6)	heatsink is higher than the bottom of the lead.							
(7)	Gage plane (foot length) to be measured from the seating plane.							

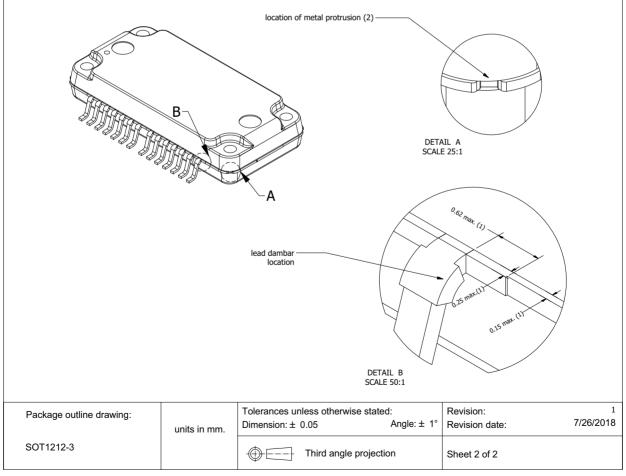


Fig 19. Package outline SOT1212-3 (sheet 2 of 2)

### 10. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C1 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1A [2]

- [1] CDM classification C1 is granted to any part that passes after exposure to an ESD pulse of 250 V.
- [2] HBM classification 1A is granted to any part that passes after exposure to an ESD pulse of 250 V.

#### 11. Abbreviations

Table 11. Abbreviations

Acronym	Description		
AM	Amplitude Modulation		
3GPP	3rd Generation Partnership Project		
CCDF	Complementary Cumulative Distribution Function		
CW	Continuous Wave		
DPCH	Dedicated Physical CHannel		
ESD	ElectroStatic Discharge		
GEN7	Seventh Generation		
GSM	Global System for Mobile Communications		
LDMOS	Laterally Diffused Metal Oxide Semiconductor		
LTE	Long Term Evolution		
MMIC	Monolithic Microwave Integrated Circuit		
MTF	Median Time to Failure		
PAR	Peak-to-Average Ratio		
PM	Phase Modulation		
RoHS	Restriction of Hazardous Substances		
VSWR	Voltage Standing-Wave Ratio		
W-CDMA	Wideband Code Division Multiple Access		

### 12. Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM7G1822S-20PB_S-20PBG v.6	20180928	Product data sheet		BLM7G1822S-20PB_S -20PBG v.5
Modifications	Section 9 on page 12: package outline versions updated			
BLM7G1822S-20PB_S-20PBG v.5	20180227	Product data sheet		BLM7G1822S-20PB_S -20PBG v.4
BLM7G1822S-20PB_S-20PBG v.4	20150901	Product data sheet		BLM7G1822S-20PB_S -20PBG v.3
BLM7G1822S-20PB_S-20PBG v.3	20150701	Product data sheet	-	BLM7G1822S-20PB_ S-20PBG v.2
BLM7G1822S-20PB_S-20PBG v.2	20140626	Objective data sheet	-	BLM7G1822S-20PB_ S-20PBG v.1
BLM7G1822S-20PB_S-20PBG v.1	20131219	Objective data sheet	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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# **BLM7G1822S-20PB(G)**

#### LDMOS 2-stage power MMIC

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## **AMPLEON**

# **BLM7G1822S-20PB(G)**

**LDMOS 2-stage power MMIC** 

### 15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information 2
2.1	Pinning
2.2	Pin description
3	Ordering information 3
4	Block diagram 3
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics4
8	Application information 5
8.1	Possible circuit topologies 8
8.2	Ruggedness in class-AB operation9
8.3	Impedance information
8.4	Graphs
9	Package outline
10	Handling information 16
11	Abbreviations
12	Revision history
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks19
14	Contact information 19
15	Contents 20

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